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Kind regards,

Team Nexperia

74CBTLV16211

24-bit bus switch

Rev. 7 — 9 November 2016

Product data sheet

1. General description

The 74CBTLV16211 provides a dual 12-bit high-speed bus switch with separate output enable inputs ($1\overline{OE}$, $2\overline{OE}$). The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The switch is disabled (high-impedance OFF-state) when the output enable ($n\overline{OE}$) input is HIGH.

To ensure the high-impedance OFF-state during power-up or power-down, $1\overline{OE}$ and $2\overline{OE}$ should be tied to the V_{CC} through a pull-up resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

Schmitt trigger action at control input makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 2.3 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Supply voltage range from 2.3 V to 3.6 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- 5 Ω switch connection between two ports
- Rail to rail switching on data I/O ports
- CMOS low power consumption
- Latch-up performance exceeds 250 mA per JESD78B Class I level A
- I_{OFF} circuitry provides partial Power-down mode operation
- TSSOP56 packages: SOT364-1 and SOT481-2
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

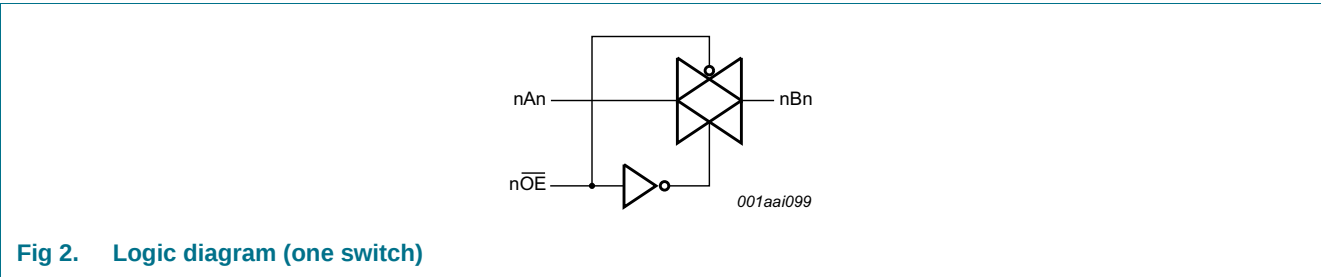
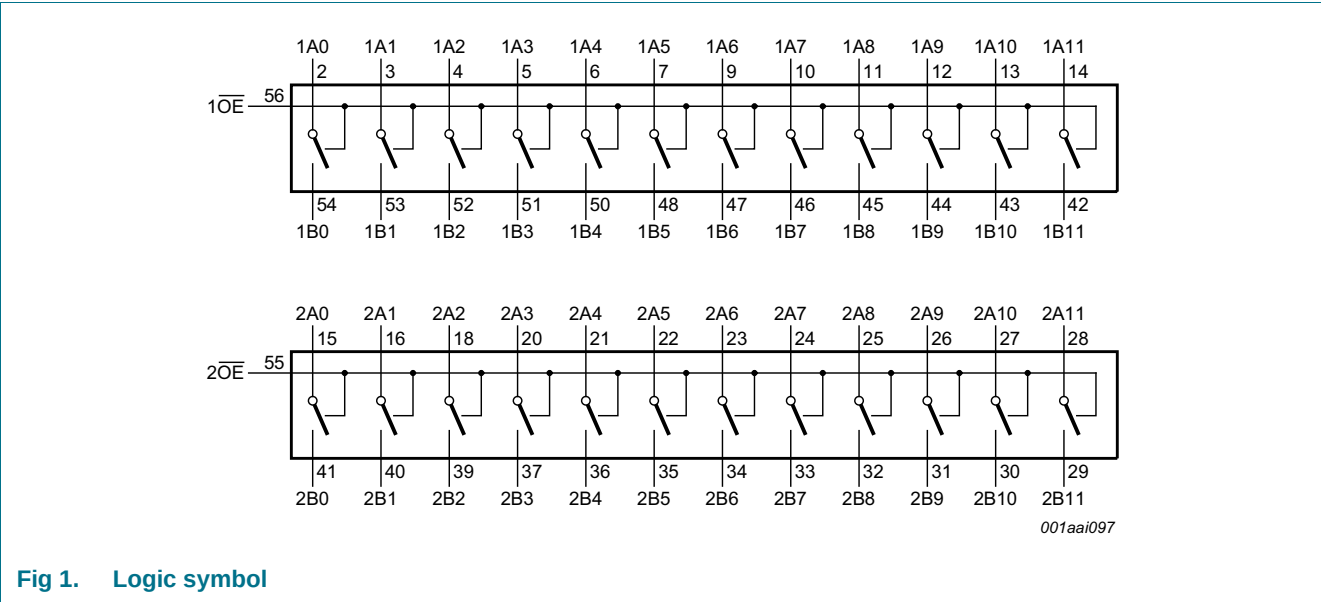


3. Ordering information

Table 1. Ordering information

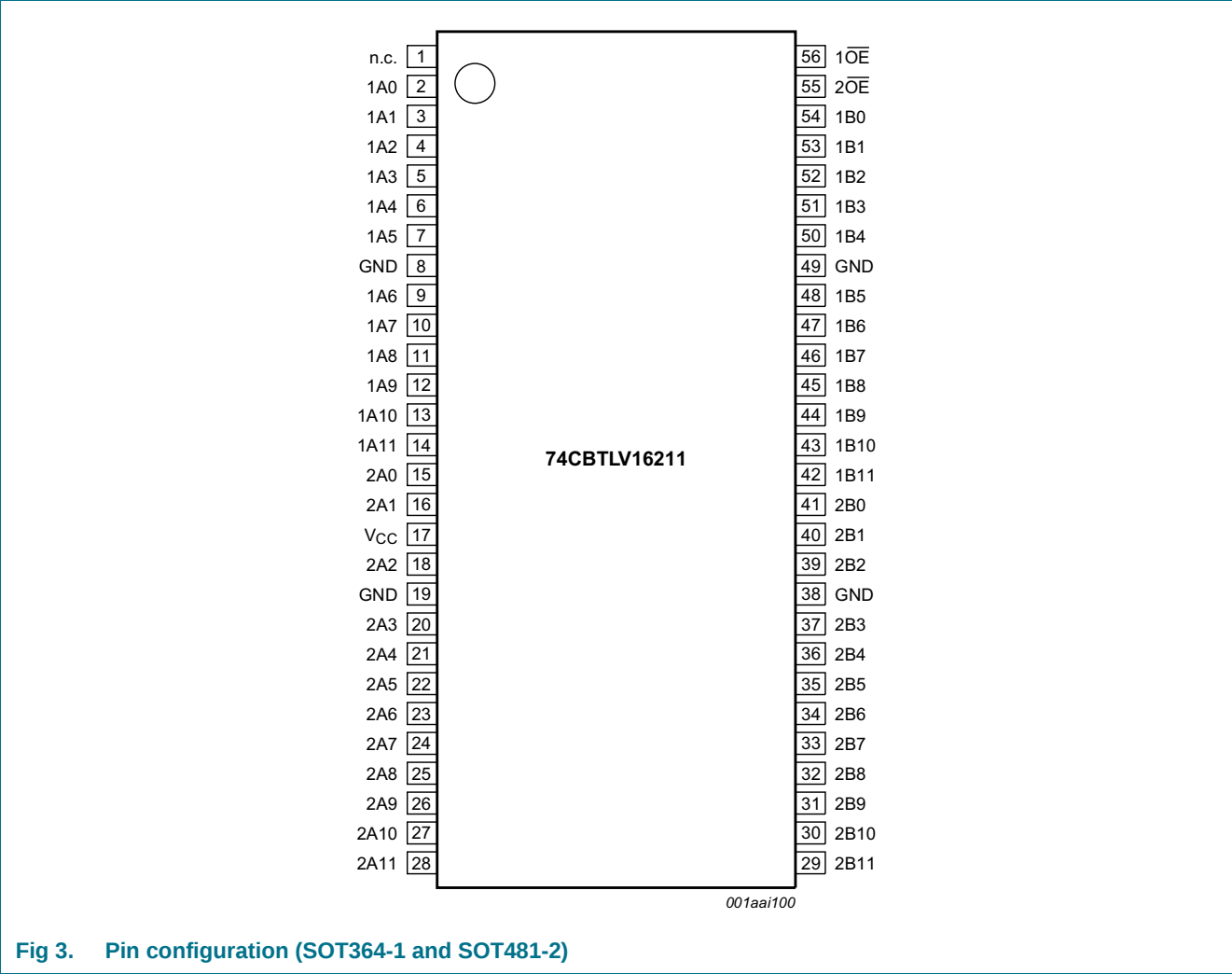
Type number	Package			Version
	Temperature range	Name	Description	
74CBTLV16211DGG	−40 °C to +125 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 6.1 mm	SOT364-1
74CBTLV16211DGV	−40 °C to +125 °C	TSSOP56	plastic thin shrink small outline package; 56 leads; body width 4.4 mm	SOT481-2

4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
n.c.	1	not connected
1A0 to 1A11	2, 3, 4, 5, 6, 7, 9, 10, 11, 12, 13, 14	independent input or output
2A0 to 2A11	15, 16, 18, 20, 21, 22, 23, 24, 25, 26, 27, 28	independent input or output
GND	8, 19, 38, 49	ground (0 V)
V _{CC}	17	supply voltage
2B0 to 2B11	41, 40, 39, 37, 36, 35, 34, 33, 32, 31, 30, 29	independent input or output

Table 2. Pin description ...continued

Symbol	Pin	Description
1B0 to 1B11	54, 53, 52, 51, 50, 48, 47, 46, 45, 44, 43, 42	independent input or output
$\overline{2OE}$	55	output enable input (active-LOW)
$\overline{1OE}$	56	output enable input (active-LOW)

6. Functional description

Table 3. Function table^[1]

Output enable input $\overline{OE}$	Function switch
L	ON-state
H	OFF-state

[1] H = HIGH voltage level; L = LOW voltage level.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_I	input voltage		-0.5	+4.6	V
V_{SW}	switch voltage	enable and disable mode	-0.5	$V_{CC} + 0.5$	V
I_{IK}	input clamping current	$V_I < -0.5$ V	-50	-	mA
I_{SK}	switch clamping current	$V_I < -0.5$ V	-50	-	mA
I_{SW}	switch current	$V_{SW} = 0$ V to V_{CC}	-	±128	mA
I_{CC}	supply current		-	+100	mA
I_{GND}	ground current		-100	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	-	600	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For TSSOP56 packages: above 55 °C the value of P_{tot} derates linearly with 8.0 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		2.3	3.6	V
V_I	input voltage		0	3.6	V
V_{SW}	switch voltage	enable and disable mode	0	V_{CC}	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 2.3$ V to 3.6 V	0	200	ns/V

[1] Applies to control signal levels.

9. Static characteristics

Table 6. Static characteristics

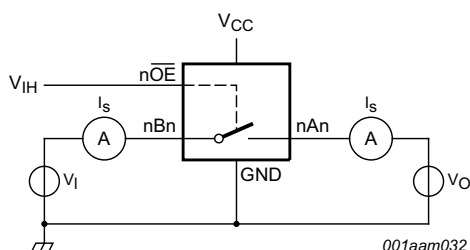
At recommended operating conditions voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	T _{amb} = -40 °C to +85 °C			T _{amb} = -40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{IH}	HIGH-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	-	0.9	V
I _I	input leakage current	pin nOE; V _I = GND to V _{CC} ; V _{CC} = 3.6 V	-	-	±1.0	-	±20	μA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 3.6 V; see Figure 4	-	-	±1	-	±20	μA
I _{S(ON)}	ON-state leakage current	V _{CC} = 3.6 V; see Figure 5	-	-	±1	-	±20	μA
I _{OFF}	power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V	-	-	±10	-	±50	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{SW} = GND or V _{CC} ; V _{CC} = 3.6 V	-	-	10	-	50	μA
ΔI _{CC}	additional supply current	pin nOE; V _I = V _{CC} - 0.6 V; V _{SW} = GND or V _{CC} ; V _{CC} = 3.6 V ^[2]	-	-	300	-	2000	μA
C _I	input capacitance	pin nOE; V _{CC} = 3.3 V; V _I = 0 V to 3.3 V	-	0.9	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance	V _{CC} = 3.3 V; V _I = 0 V to 3.3 V	-	5.2	-	-	-	pF
C _{S(ON)}	ON-state capacitance	V _{CC} = 3.3 V; V _I = 0 V to 3.3 V	-	14.3	-	-	-	pF

[1] All typical values are measured at T_{amb} = 25 °C.

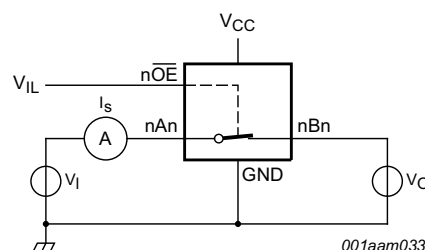
[2] One input at 3 V, other inputs at V_{CC} or GND.

9.1 Test circuits



V_I = V_{CC} or GND and V_O = GND or V_{CC}.

Fig 4. Test circuit for measuring OFF-state leakage current (one channel)



V_I = V_{CC} or GND and V_O = open circuit.

Fig 5. Test circuit for measuring ON-state leakage current (one channel)

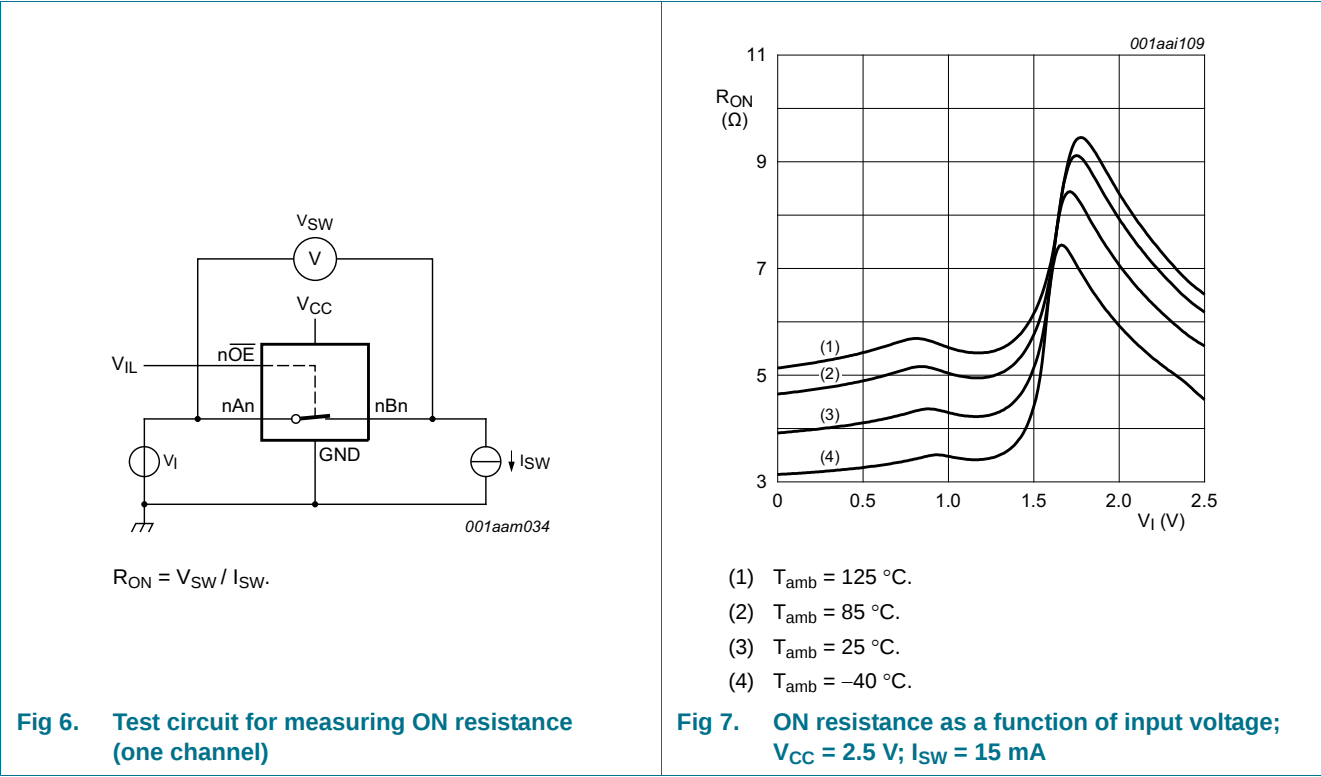
9.2 ON resistance

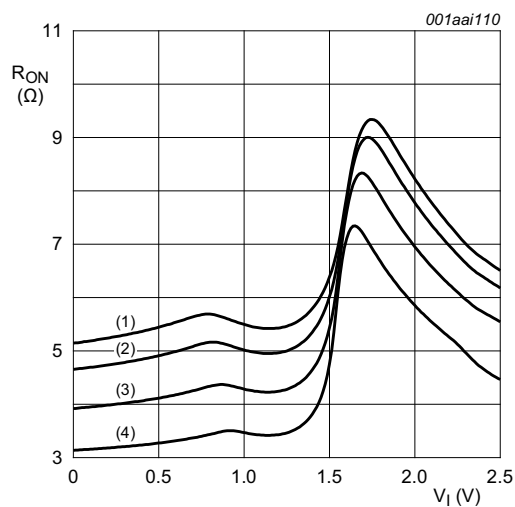
Table 7. Resistance R_{ON}
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions	T _{amb} = −40 °C to +85 °C			T _{amb} = −40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
R _{ON}	ON resistance	V _{CC} = 2.3 V to 2.7 V; see Figure 7 to Figure 9						
		I _{SW} = 64 mA; V _I = 0 V	-	4.2	8.0	-	15.0	Ω
		I _{SW} = 24 mA; V _I = 0 V	-	4.2	8.0	-	15.0	Ω
		I _{SW} = 15 mA; V _I = 1.7 V	-	8.4	40	-	60.0	Ω
		V _{CC} = 3.0 V to 3.6 V; see Figure 10 to Figure 12						
		I _{SW} = 64 mA; V _I = 0 V	-	4.0	7.0	-	11.0	Ω
		I _{SW} = 24 mA; V _I = 0 V	-	4.0	7.0	-	11.0	Ω
		I _{SW} = 15 mA; V _I = 2.4 V	-	6.2	15	-	25.5	Ω

- [1] Typical values are measured at T_{amb} = 25 °C and nominal V_{CC}.
- [2] Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

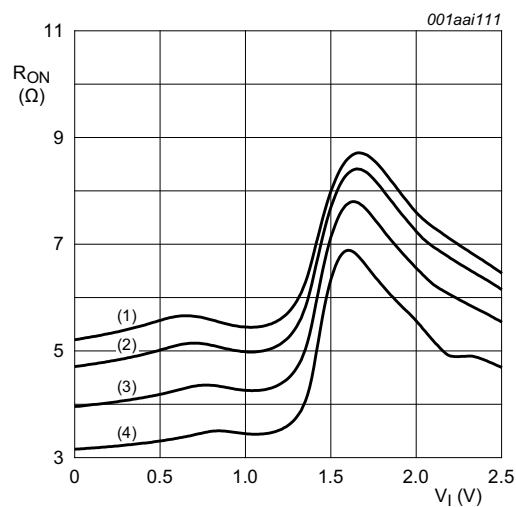
9.3 ON resistance test circuit and graphs





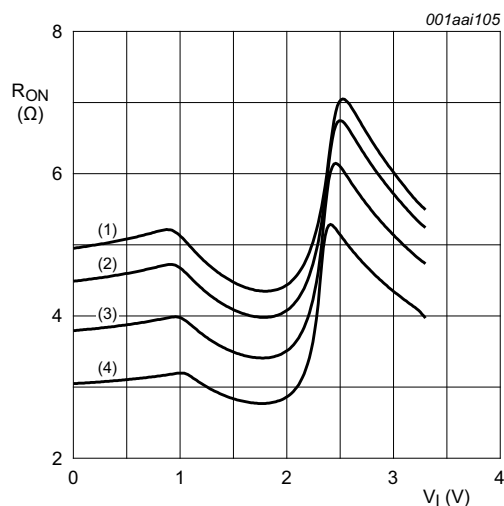
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 8. ON resistance as a function of input voltage;
 $V_{CC} = 2.5\text{ V}; I_{SW} = 24\text{ mA}$



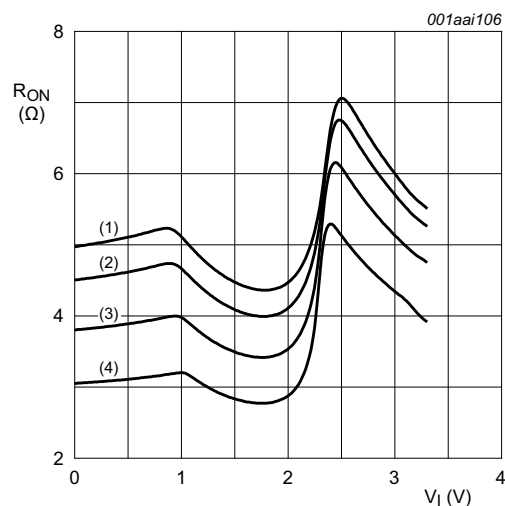
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 9. ON resistance as a function of input voltage;
 $V_{CC} = 2.5\text{ V}; I_{SW} = 64\text{ mA}$



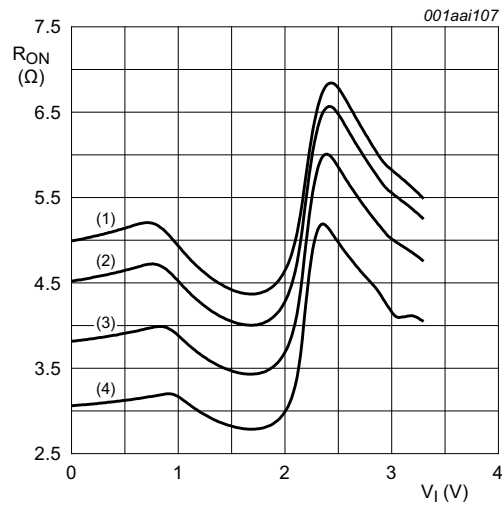
- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 10. ON resistance as a function of input voltage;
 $V_{CC} = 3.3\text{ V}; I_{SW} = 15\text{ mA}$



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}.$
- (2) $T_{amb} = 85\text{ }^{\circ}\text{C}.$
- (3) $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (4) $T_{amb} = -40\text{ }^{\circ}\text{C}.$

Fig 11. ON resistance as a function of input voltage;
 $V_{CC} = 3.3\text{ V}; I_{SW} = 24\text{ mA}$



- (1) $T_{amb} = 125\text{ }^{\circ}\text{C}$.
 (2) $T_{amb} = 85\text{ }^{\circ}\text{C}$.
 (3) $T_{amb} = 25\text{ }^{\circ}\text{C}$.
 (4) $T_{amb} = -40\text{ }^{\circ}\text{C}$.

Fig 12. ON resistance as a function of input voltage; $V_{CC} = 3.3\text{ V}$; $I_{SW} = 64\text{ mA}$

10. Dynamic characteristics

Table 8. Dynamic characteristics

$GND = 0\text{ V}$; for test circuit see [Figure 15](#)

Symbol	Parameter	Conditions	$T_{amb} = -40\text{ }^{\circ}\text{C to } +85\text{ }^{\circ}\text{C}$			$T_{amb} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$		Unit
			Min	Typ ^[1]	Max	Min	Max	
t_{pd}	propagation delay	nAn to nBn or nBn to nAn; see Figure 13						
		$V_{CC} = 2.3\text{ V to } 2.7\text{ V}$	-	-	0.13	-	0.2	ns
		$V_{CC} = 3.0\text{ V to } 3.6\text{ V}$	-	-	0.2	-	0.31	ns
t_{en}	enable time	$\overline{\text{nOE}}$ to nAn or nBn; see Figure 14						
		$V_{CC} = 2.3\text{ V to } 2.7\text{ V}$	1.0	2.0	7.0	1.0	7.8	ns
		$V_{CC} = 3.0\text{ V to } 3.6\text{ V}$	1.0	1.7	6.2	1.0	6.8	ns
t_{dis}	disable time	$\overline{\text{nOE}}$ to nAn or nBn; see Figure 14						
		$V_{CC} = 2.3\text{ V to } 2.7\text{ V}$	1.0	2.6	7.2	1.0	8.1	ns
		$V_{CC} = 3.0\text{ V to } 3.6\text{ V}$	1.0	3.0	7.7	1.0	8.8	ns

- [1] All typical values are measured at $T_{amb} = 25\text{ }^{\circ}\text{C}$ and at nominal V_{CC} .
 [2] The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the load capacitance, when driven by an ideal voltage source (zero output impedance).
 [3] t_{pd} is the same as t_{PLH} and t_{PHL} .
 [4] t_{en} is the same as t_{PZH} and t_{PZL} .
 [5] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

11. Waveforms

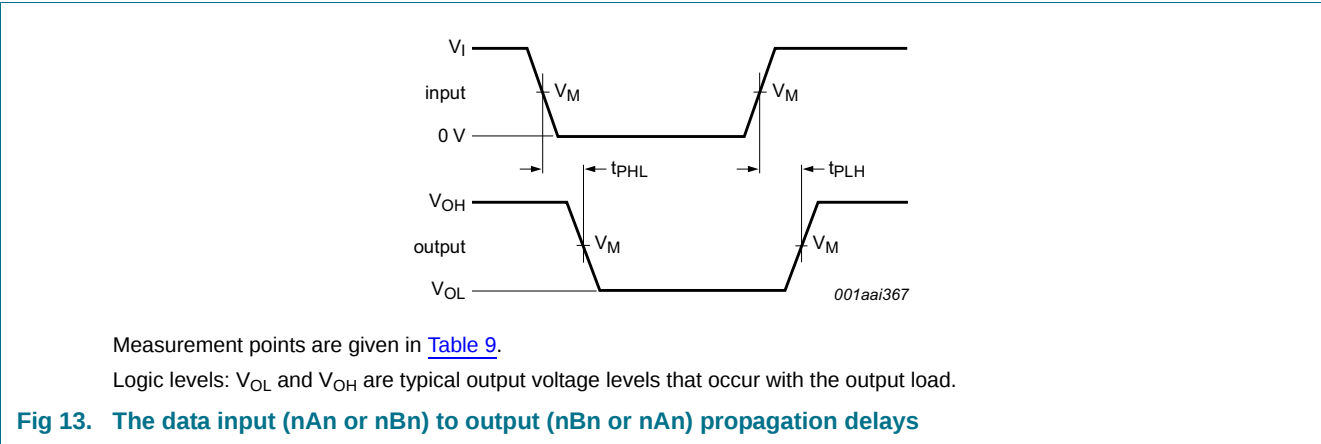
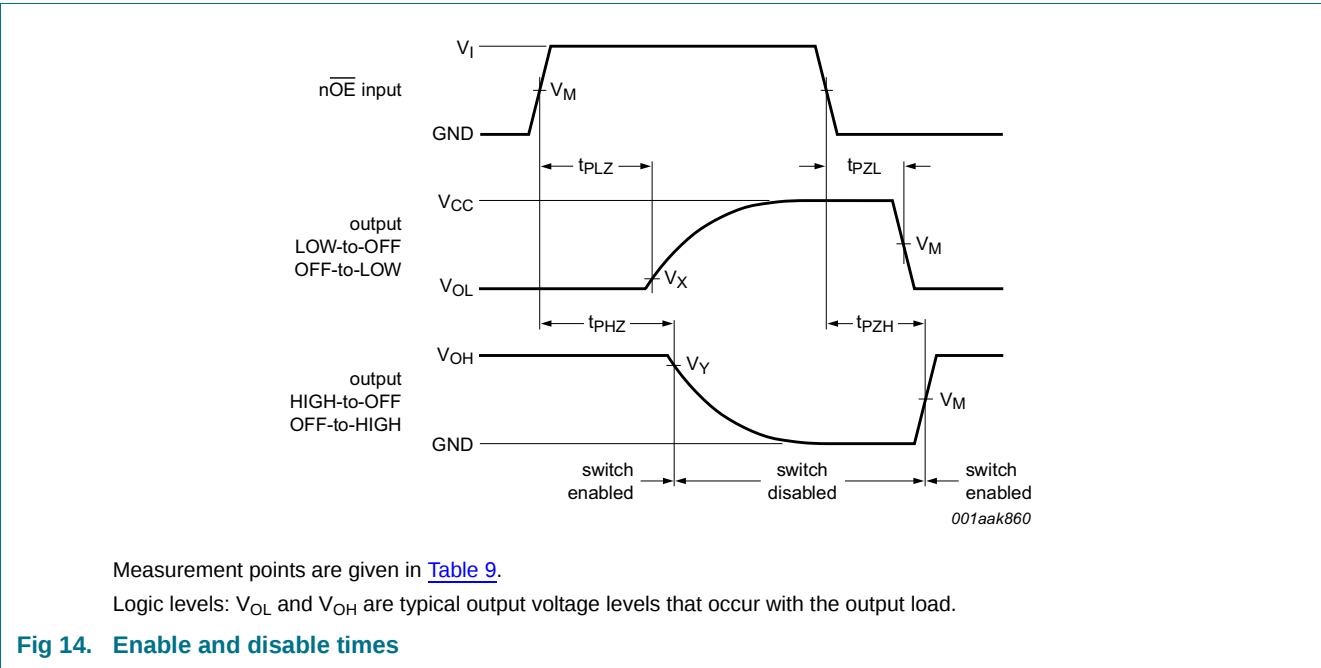
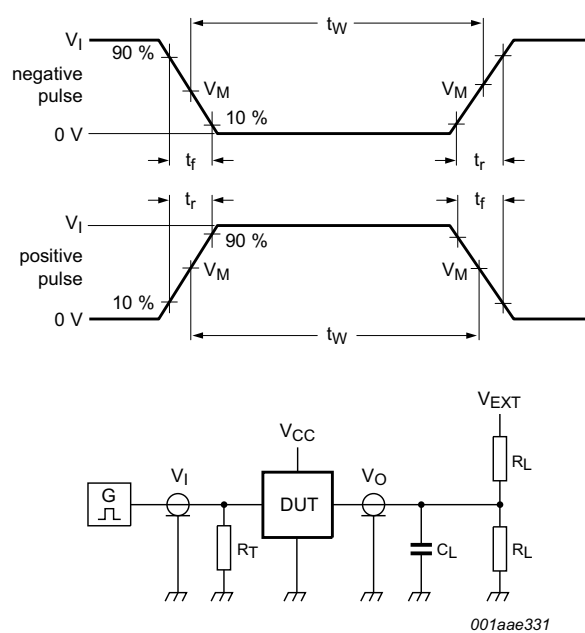


Table 9. Measurement points

Supply voltage	Input			Output		
V_{CC}	V_M	V_I	$t_r = t_f$	V_M	V_X	V_Y
2.3 V to 2.7 V	$0.5V_{CC}$	V_{CC}	≤ 2.0 ns	$0.5V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
3.0 V to 3.6 V	$0.5V_{CC}$	V_{CC}	≤ 2.0 ns	$0.5V_{CC}$	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V





Test data is given in [Table 10](#).
Definitions for test circuit:
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.
 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.
 V_{EXT} = External voltage for measuring switching times.

Fig 15. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load		V_{EXT}		
V_{CC}	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
2.3 V to 2.7 V	30 pF	500 Ω	open	GND	$2V_{CC}$
3.0 V to 3.6 V	50 pF	500 Ω	open	GND	$2V_{CC}$

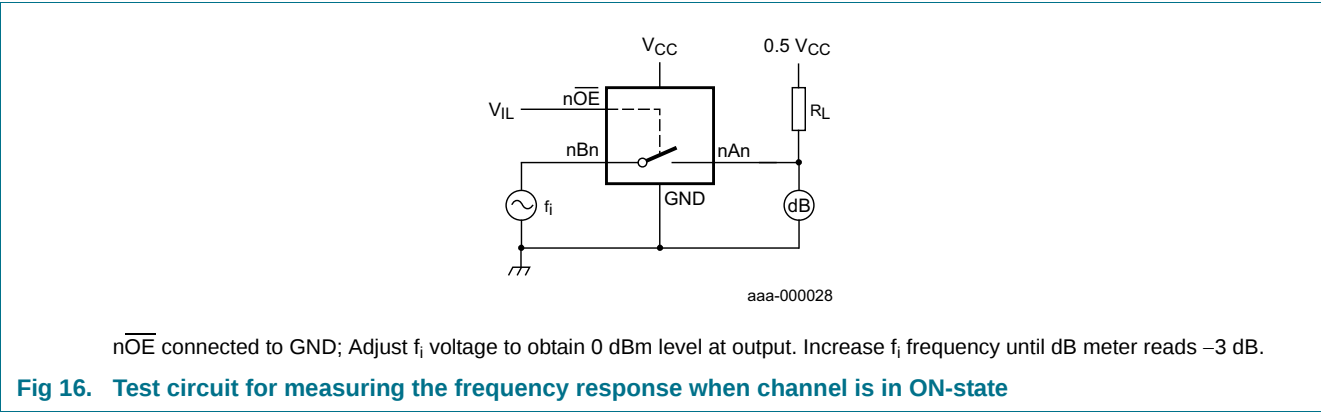
11.1 Additional dynamic characteristics

Table 11. Additional dynamic characteristics
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = \text{GND}$ or V_{CC} (unless otherwise specified); $t_r = t_f \leq 2.5 \text{ ns}$.

Symbol	Parameter	Conditions	T _{amb} = 25 °C			Unit
			Min	Typ	Max	
f _(-3dB)	−3 dB frequency response	V _{CC} = 3.3 V; R _L = 50 Ω; see Figure 16 ^[1]	-	458	-	MHz

[1] f_i is biased at 0.5V_{CC}.

11.2 Test circuits



12. Package outline

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 6.1 mm SOT364-1

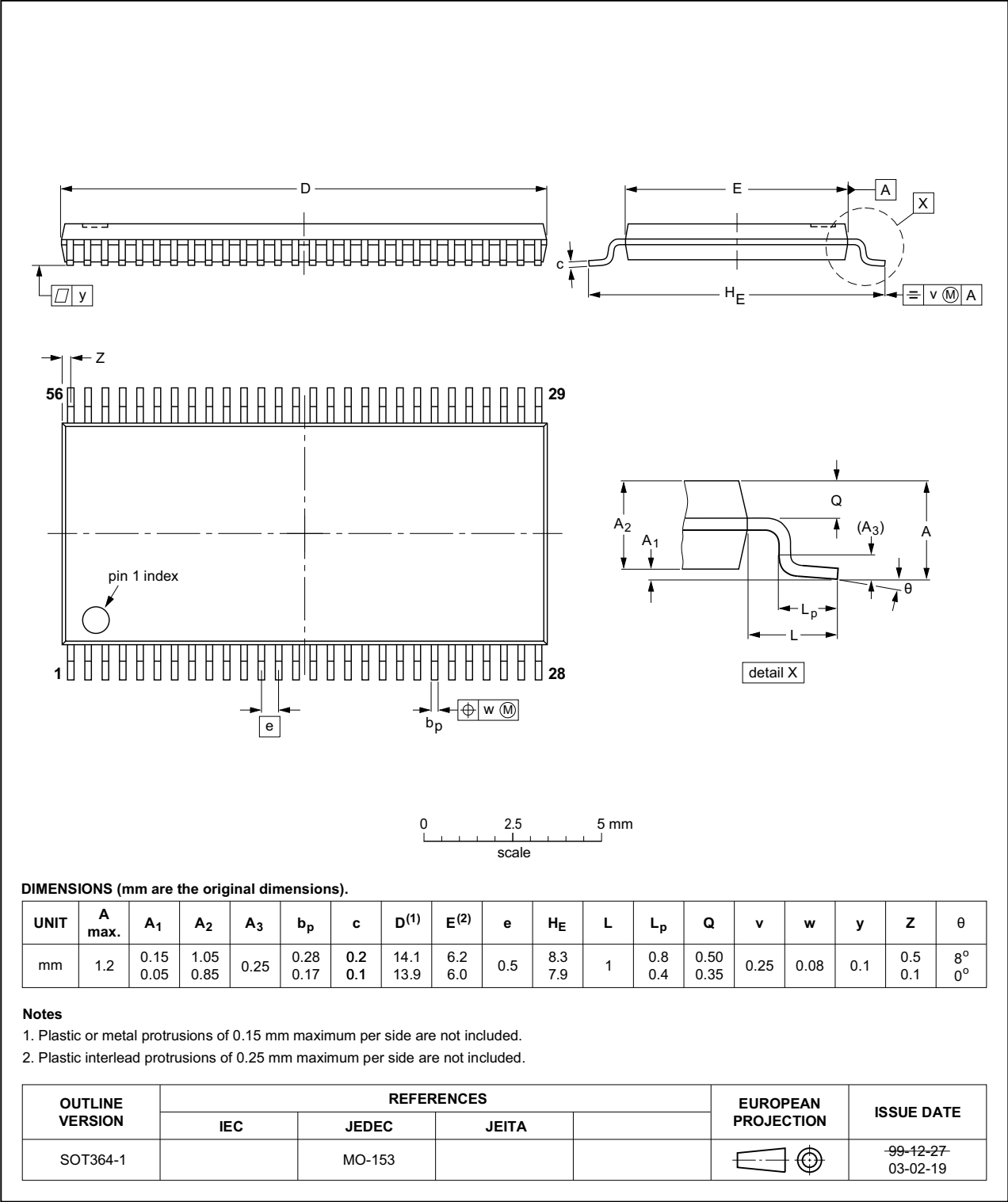


Fig 17. Package outline SOT364-1 (TSSOP56)

TSSOP56: plastic thin shrink small outline package; 56 leads; body width 4.4 mm

SOT481-2

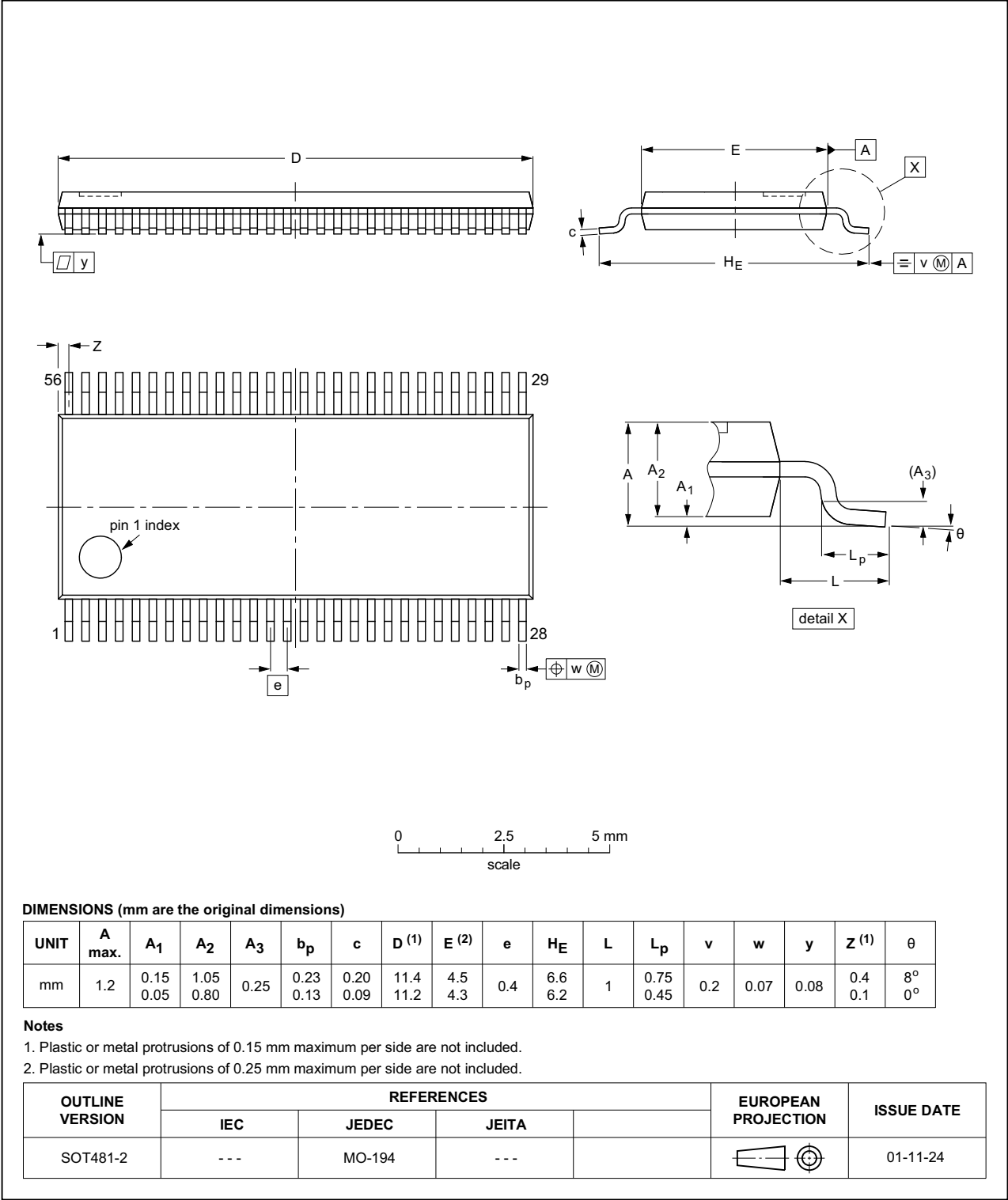


Fig 18. Package outline SOT481-2 (TSSOP56)

13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74CBTLV16211 v.7	20161109	Product data sheet	-	74CBTLV16211 v.6
Modifications:	• Section 11.1 and Section 11.2 added.			
74CBTLV16211 v.6	20111215	Product data sheet	-	74CBTLV16211 v.5
Modifications:	• Legal pages updated.			
74CBTLV16211 v.5	20101230	Product data sheet	-	74CBTLV16211 v.4
74CBTLV16211 v.4	20100816	Product data sheet	-	74CBTLV16211 v.3
74CBTLV16211 v.3	20100112	Product data sheet	-	74CBTLV16211 v.2
74CBTLV16211 v.2	20090826	Product data sheet	-	74CBTLV16211 v.1
74CBTLV16211 v.1	20080620	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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